MIL-S-19500/352 (EL)
AMENDMENT 1
10 September 1971

MILITARY SPECIFICATION

SEMICONDUCTOR DEVICE, DIODE, SILICON

TYPE 1N831A

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Paragraph 4.3.1. , Test conditions, change "P=5.0 mw" to read: "P=0.5 mw"

Custodian:
Army-EL

Preparing activity:
Army-EL
Project no. 5961-A364

FSC 5961